

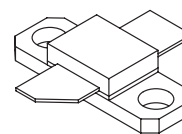
The RF Line
NPN Silicon
RF Power Transistor

MRF16006

6.0 WATTS, 1.6 GHz
RF POWER TRANSISTOR
NPN SILICON

Designed for 28 Volt microwave large-signal, common base, Class-C CW amplifier applications in the range 1600 – 1640 MHz.

- Specified 28 Volt, 1.6 GHz Class-C Characteristics
Output Power = 6 Watts
Minimum Gain = 7.4 dB, @ 6 Watts
Minimum Efficiency = 40% @ 6 Watts
- Characterized with Series Equivalent Large-Signal Parameters from 1500 MHz to 1700 MHz
- Silicon Nitride Passivated
- Gold Metallized, Emitter Ballasted for Long Life and Resistance to Metal Migration



CASE 395C-01, STYLE 2

MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

| Rating | Symbol | Value | Unit |
|--|-----------|-------------|------------------------------|
| Collector-Emitter Voltage | V_{CES} | 60 | Vdc |
| Emitter-Base Voltage | V_{EBO} | 4.0 | Vdc |
| Collector-Current | I_C | 1.0 | Adc |
| Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C | P_D | 26 0.15 | Watts W/ $^\circ\text{C}$ |
| Storage Temperature Range | T_{stg} | -65 to +150 | $^\circ\text{C}$ |

THERMAL CHARACTERISTICS

| | | | |
|---|-----------------|-----|---------------------------|
| Thermal Resistance — Junction to Case (1) (2) | $R_{\theta JC}$ | 6.8 | $^\circ\text{C}/\text{W}$ |
|---|-----------------|-----|---------------------------|

(1) Thermal measurement performed using CW RF operating condition.

(2) Thermal resistance is determined under specified RF operating conditions by infrared measurement techniques.

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|----------------|--------|-----|-----|-----|------|
|----------------|--------|-----|-----|-----|------|

OFF CHARACTERISTICS

| | | | | | |
|--|---------------|-----|---|-----|------|
| Collector–Emitter Breakdown Voltage ($I_C = 40\text{ mAdc}$, $V_{BE} = 0$) | $V_{(BR)CES}$ | 55 | — | — | Vdc |
| Collector–Base Breakdown Voltage ($I_C = 40\text{ mAdc}$, $I_E = 0$) | $V_{(BR)CBO}$ | 55 | — | — | Vdc |
| Emitter–Base Breakdown Voltage ($I_E = 2.5\text{ mAdc}$, $I_C = 0$) | $V_{(BR)EBO}$ | 4.0 | — | — | Vdc |
| Collector Cutoff Current ($V_{CE} = 28\text{ Vdc}$, $V_{BE} = 0$) | I_{CES} | — | — | 2.5 | mAdc |

ON CHARACTERISTICS

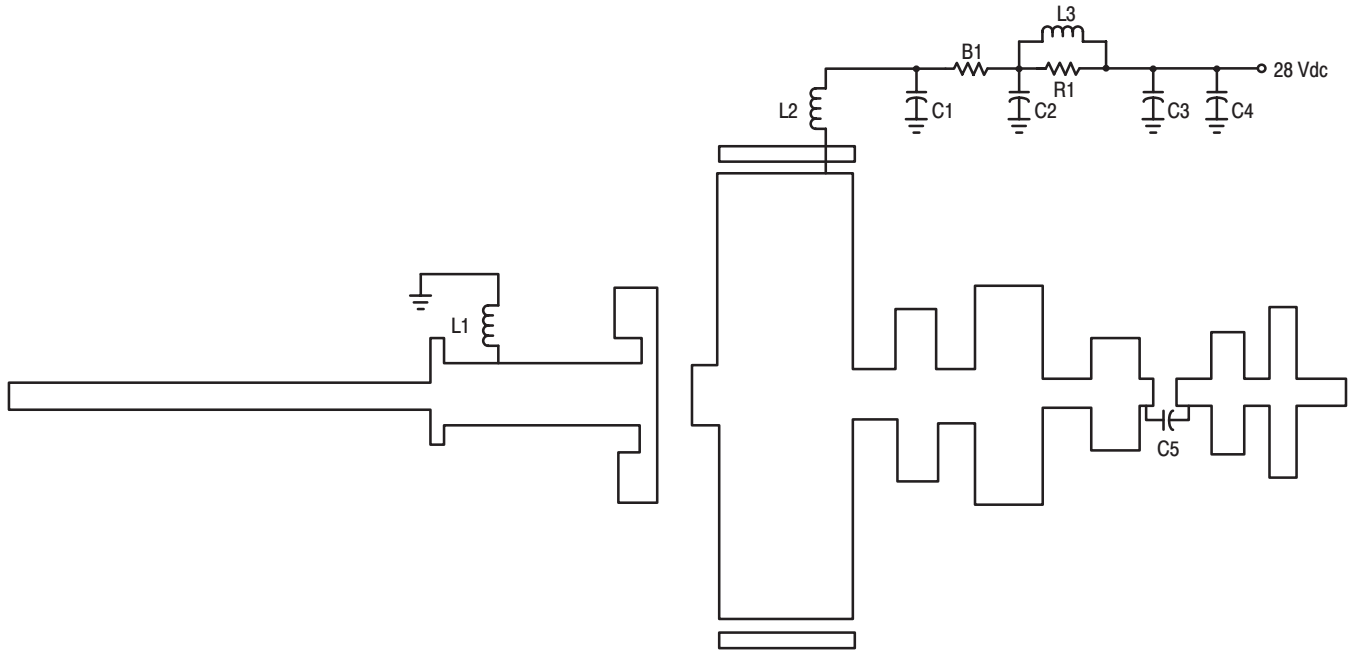
| | | | | | |
|--|----------|----|---|----|---|
| DC Current Gain ($I_{CE} = 0.2\text{ Adc}$, $V_{CE} = 5.0\text{ Vdc}$) | h_{FE} | 20 | — | 80 | — |
|--|----------|----|---|----|---|

DYNAMIC CHARACTERISTICS

| | | | | | |
|---|----------|----|---|---|----|
| Output Capacitance ($V_{CB} = 28\text{ Vdc}$, $f = 1.0\text{ MHz}$) | C_{ob} | 11 | — | — | pf |
|---|----------|----|---|---|----|

FUNCTIONAL TESTS

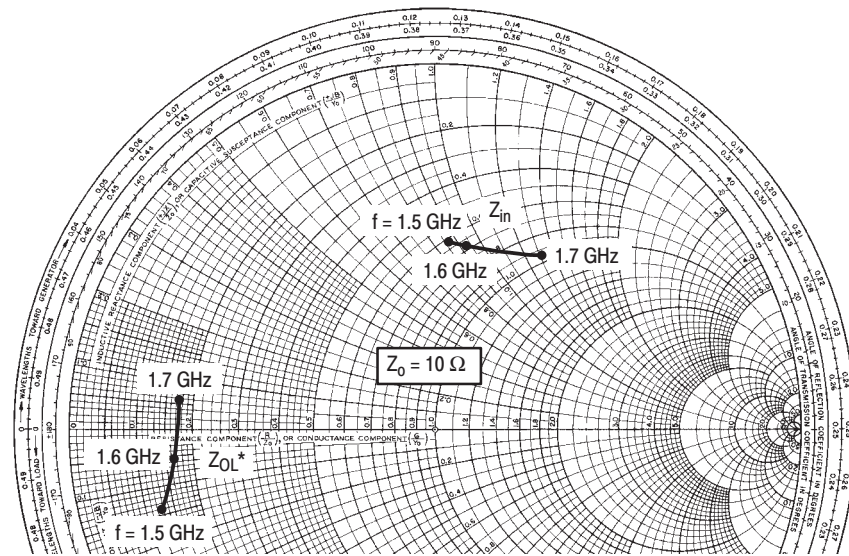
| | | | | | |
|---|----------|--------------------------------|-----|---|----|
| Common–Base Amplifier Power Gain ($V_{CC} = 28\text{ Vdc}$, $P_{out} = 6\text{ Watts}$, $f = 1600/1640\text{ MHz}$) | G_{pe} | 7.4 | — | — | dB |
| Collector Efficiency ($V_{CC} = 28\text{ Vdc}$, $P_{out} = 6\text{ Watts}$, $f = 1600/1640\text{ MHz}$) | η | 40 | 45 | — | % |
| Return Loss ($V_{CC} = 28\text{ Vdc}$, $P_{out} = 6\text{ Watts}$, $f = 1600/1640\text{ MHz}$) | I_{RL} | — | 8.0 | — | dB |
| Output Mismatch Stress ($V_{CC} = 28\text{ Vdc}$, $P_{out} = 6\text{ Watts}$, $f = 1600\text{ MHz}$, Load VSWR = 3:1 all phase angles at frequency of test) | ψ | No Degradation in Output Power | | | |



Board Material – Teflon® Glass Laminate Dielectric
 Thickness – 0.30", $\epsilon_r = 2.55$ ", 2.0 oz. Copper

- | | | | |
|--------|------------------------------|--------|--------------------------------------|
| B1 | Fair Rite Bead on #24 Wire | C4 | 47 μ F, 50 V, Electrolytic Cap |
| C1, C5 | 100 pF, B Case, ATC Chip Cap | L1, L2 | 3 Turns, #18, 0.133" ID, 0.15" Long |
| C2 | 0.1 μ F, Dipped Mica Cap | L3 | 9 Turns, #24 Enamel |
| C3 | 0.1 μ F, Chip Cap | R1 | 82 Ω , 1.0 W, Carbon Resistor |

Figure 1. MRF16006 Test Fixture Schematic



$V_{CC} = 28$ Vdc, $P_{out} = 6$ W

| f MHz | Z_{in} Ohms | Z_{OL}^* Ohms |
|----------|------------------|--------------------|
| 1500 | 6.28 + j 8.53 | 1.22 - j 1.37 |
| 1600 | 7.04 + j 9.00 | 1.58 - j 0.53 |
| 1700 | 9.55 + j 12.86 | 1.71 + j 0.39 |

Z_{OL}^* = Conjugate of the optimum load impedance into which the device output operates at a given output power, voltage and frequency.

Figure 2. Series Equivalent Input/Output Impedance

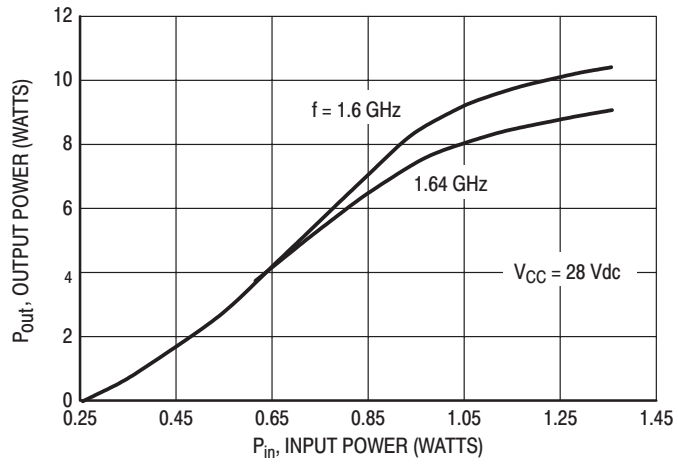
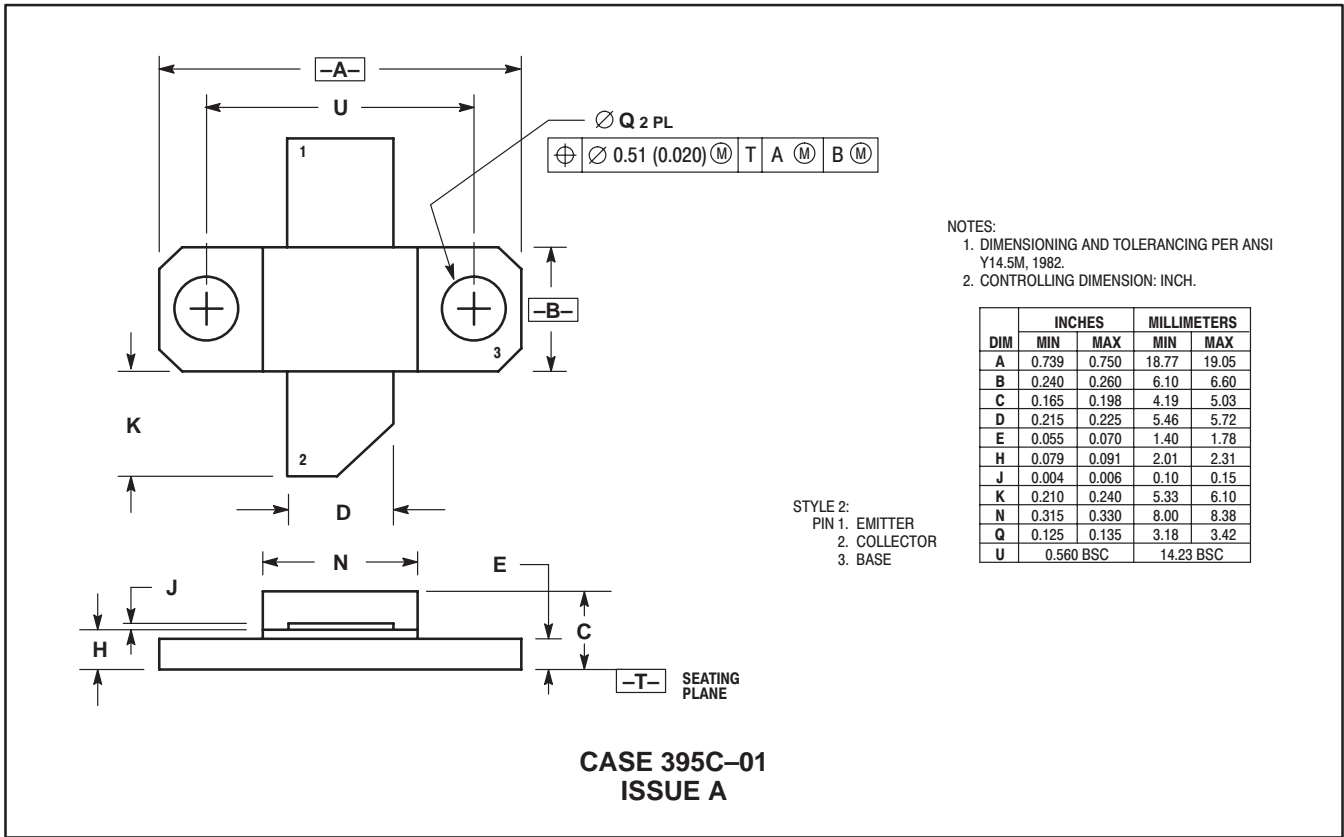


Figure 3. Output Power versus Input Power

PACKAGE DIMENSIONS



NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

| DIM | INCHES | | MILLIMETERS | |
|-----|-----------|-------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | 0.739 | 0.750 | 18.77 | 19.05 |
| B | 0.240 | 0.260 | 6.10 | 6.60 |
| C | 0.165 | 0.198 | 4.19 | 5.03 |
| D | 0.215 | 0.225 | 5.46 | 5.72 |
| E | 0.055 | 0.070 | 1.40 | 1.78 |
| H | 0.079 | 0.091 | 2.01 | 2.31 |
| J | 0.004 | 0.006 | 0.10 | 0.15 |
| K | 0.210 | 0.240 | 5.33 | 6.10 |
| N | 0.315 | 0.330 | 8.00 | 8.38 |
| Q | 0.125 | 0.135 | 3.18 | 3.42 |
| U | 0.560 BSC | | 14.23 BSC | |

STYLE 2:
 PIN 1. EMITTER
 2. COLLECTOR
 3. BASE

Specifications subject to change without notice.

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